

## NTE999SM Integrated Circuit Programmable Precision Reference

### **Description:**

The NTE999SM integrated circuit is a three-terminal programmable shunt regulator. This monolithic IC voltage reference operates as a low temperature coefficient zener which is programmable from  $V_{ref}$  to 36 volts with two external resistors. This device exhibits a wide operating current range of 1.0 to 100mA with a typical dynamic impedance of  $0.22\Omega$ . The characteristics of this reference make it an excellent replacement for zener diodes in many applications such as digital voltmeters, power supplies, and op amp circuitry. The 2.5 volt reference makes it convenient to obtain a stable reference from 5.0 volt logic supplies, and since the NTE999SM operates as a shunt regulator, it can be used as either a positive or negative voltage reference.

### **Features:**

- Programmable Output Voltage to 36 Volts
- Voltage Reference Tolerance:  $\pm 1.0\%$
- Low Dynamic Output Impedance:  $0.22\Omega$  Typical
- Sink Current Capability of 1.0 to 100mA
- Equivalent Full Range Temperature Coefficient of 50ppm/ $^{\circ}\text{C}$  Typical
- Temperature Compensated for Operation over Full Rated Operating Temperature Range
- Low Output Noise Voltage.

### **Absolute Maximum Ratings:** ( $T_A = 0^{\circ}$ to $+70^{\circ}\text{C}$ , unless otherwise noted.)

|  |   |
|--|---|
| Cathode to Anode Voltage, $V_{KA}$ .....                                       | 37V                                     |
| Cathode Current Range, Continuous, $I_K$ .....                                 | -100 to +150mA                          |
| Reference Input Current Range, Continuous, $I_{ref}$ .....                     | -0.05 to +10mA                          |
| Total Power Dissipation ( $T_A = +25^{\circ}\text{C}$ ), $P_D$ .....           | 725mW                                   |
| Derate Above $25^{\circ}\text{C}$ .....  | 5.8mW/ $^{\circ}\text{C}$               |
| Operating Junction Temperature, $T_J$ .....                                    | $+150^{\circ}\text{C}$                  |
| Operating Ambient Temperature Range, $T_A$ .....                               | $0^{\circ}$ to $+70^{\circ}\text{C}$    |
| Storage Temperature Range, $T_{stg}$ .....                                     | $-65^{\circ}$ to $+150^{\circ}\text{C}$ |
| Thermal Resistance, Junction-to-Ambient, $R_{thJA}$ .....                      | 178 $^{\circ}\text{C}/\text{W}$         |
| Thermal Resistance, Junction-to-Case, $R_{thJC}$ .....                         | 83 $^{\circ}\text{C}/\text{W}$          |
| Lead Temperature (During Soldering, 1/16" if from case for 10sec), $T_L$ ..... | $+260^{\circ}\text{C}$                  |

**Recommended Operating Conditions**Cathode to Anode Voltage,  $V_{KA}$ Cathode Current,  $I_K$ **Min****Max****Unit** $V_{ref}$ 

36

V

1.0

100

mA

**Electrical Characteristics** ( $T_A = +25^\circ\text{C}$  unless otherwise noted)

| Characteristic   | Symbol                                 | Min    | Typ          | Max          | Unit          |
|--|--|--------|--------------|--------------|---------------|
| Reference Input Voltage<br>$V_{KA} = V_{ref}$ , $I_K = 10\text{mA}$<br>$T_A = +25^\circ\text{C}$   | $V_{ref}$                              | 2.470  | 2.495        | 2.520        | V             |
| Reference Input Voltage Deviation Over Temperature Range (Note 1, 2)<br>$V_{KA} = V_{ref}$ , $I_K = 10\text{mA}$   | $\Delta V_{ref}$                       | –      | 3.0          | 17           | mV            |
| Ratio of Change in Reference Input Voltage to Change in Cathode to Anode Voltage<br>$I_K = 10\text{mA}$ ,<br>$\Delta V_{KA} = 10\text{V to } V_{ref}$<br>$\Delta V_{KA} = 36\text{V to } 10\text{V}$ | $\frac{\Delta V_{ref}}{\Delta V_{KA}}$ | –<br>– | –1.4<br>–1.0 | –2.7<br>–2.0 | mV/V          |
| Reference Input Current<br>$I_K = 10\text{mA}$ , $R1 = 10\text{k}$ , $R2 = \infty$<br>$T_A = +25^\circ\text{C}$<br>$T_A = T_{low} \text{ to } T_{high}$ (Note 1)                                     | $I_{ref}$                              | –<br>– | 1.8<br>–     | 4.0<br>5.2   | $\mu\text{A}$ |
| Reference Input Current Deviation Over Temperature Range (Note 1)<br>$I_K = 10\text{mA}$ , $R1 = 10\text{k}$ , $R2 = \infty$   | $\Delta I_{ref}$                       | –      | 1.8          | 4.0          | $\mu\text{A}$ |
| Minimum Cathode Current for Regulation<br>$V_{KA} = V_{ref}$   | $I_{min}$                              | –      | 0.5          | 1.0          | mA            |
| Off-State Cathode Current<br>$V_{KA} = 36\text{V}$ , $V_{ref} = 0\text{V}$   | $I_{off}$                              | –      | 2.6          | 1000         | nA            |
| Dynamic Impedance (Note 3)<br>$V_{KA} = V_{ref}$ , $\Delta I_K = 1.0\text{mA to } 100\text{mA}$<br>$f \leq 1.0\text{kHz}$  | $ Z_{ka} $                             | –      | 0.22         | 0.5          | $\Omega$      |

Note 1:  $T_{low} = 0^\circ\text{C}$ ,  $T_{high} = +70^\circ\text{C}$ Note 2: The deviation parameter  $\Delta V_{ref}$  is defined as the differences between the maximum and minimum values obtained over the full operating ambient temperature range that applies.

$$\Delta V_{ref} = V_{ref}^{Max} - V_{ref}^{Min}$$

$$\Delta T_A = T_2 - T_1$$

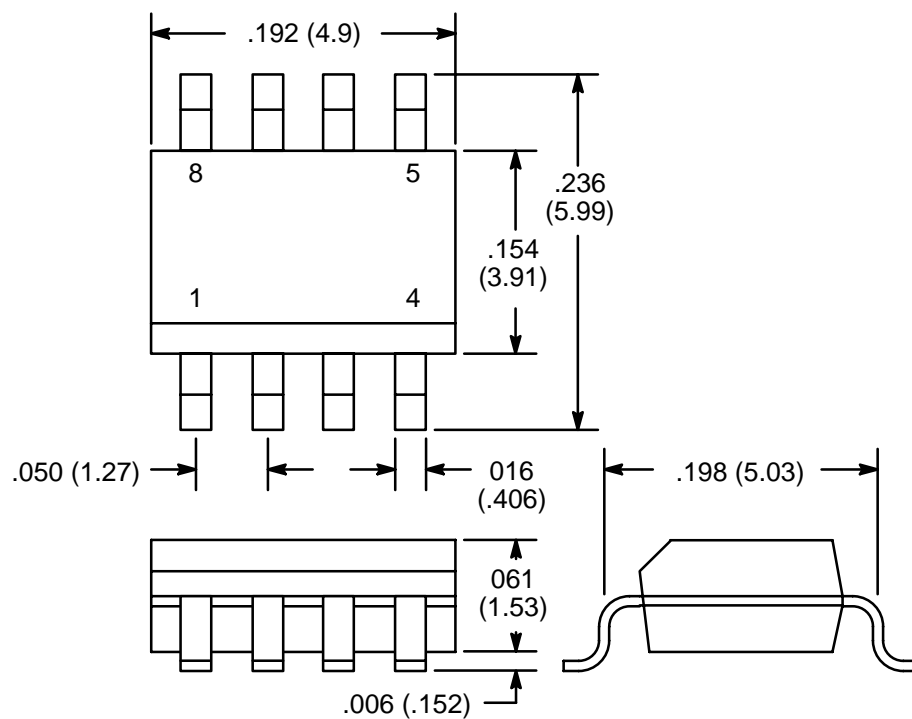
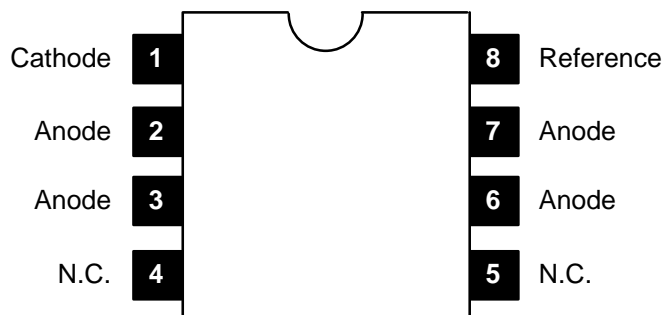
Note 2: (cont'd) The average temperature coefficient of the reference input voltage,  $\alpha V_{ref}$ , is defined as:

$$\alpha V_{ref} \frac{\text{ppm}}{^\circ\text{C}} = \frac{\left( \frac{\Delta V_{ref}}{V_{ref} @ 25^\circ\text{C}} \right) \times 10^6}{\Delta T_A} = \frac{\Delta V_{ref} \times 10^6}{\Delta T_A (V_{ref} @ 25^\circ\text{C})}$$

 $\alpha V_{ref}$  can be positive or negative depending on whether  $V_{ref}^{Min}$  or  $V_{ref}^{Max}$  occurs at the lower ambient temperature.

When the device is programmed with two external resistors, R1 and R2, the total dynamic impedance of the circuit is defined as:

$$|Z_{ka}'| \approx |Z_{ka}| \left( 1 + \frac{R1}{R2} \right)$$



NOTE: Pin1 on Beveled Edge